# NSN 5961-00-851-4532

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#### Inclosure Material:

Metal

**Overall Length:** 

0.380 inches

### Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.438 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

200.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

20.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug

# **Specification Data:**

80131-release4410 professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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